Diode Semiconductor Device - Page 1 of 1



reflect specification type data in specification

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Inclosure Material:	
Metal	
Overall Length:	
Between 0.195 inches and 0.371 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.215 inches and 0.265 inches	
Electrode Internally-electrically Connected To Case:	
Cathode	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
5.6 regulator voltage	
Voltage Tolerance In Percent:	
-5.0 to 5.0	
Current Rating Per Characteristic:	
45.00 milliamperes all primaries horsepower metric and 162.00 milliamperes dc current in reverse breakdown regio	on
Power Rating Per Characteristic:	
1.0 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification typ	e data in specific
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type	data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Specification Data:	
81349-mil-prf19500/115 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Filg:	
A110a0	
Mil-std (military Standard):	
Mil-prf-19500 spec.	
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